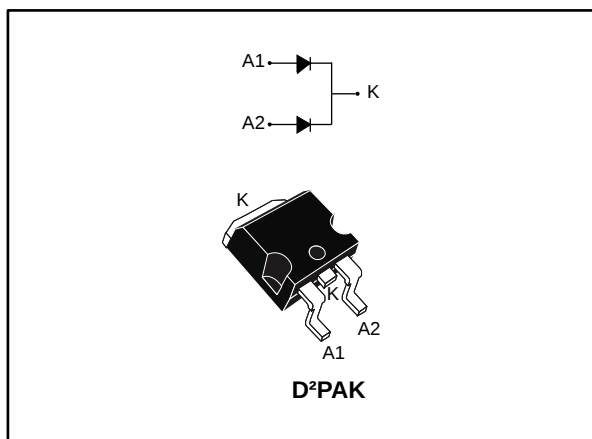


Automotive high efficiency ultrafast diode

Datasheet - production data



Description

Dual center tap rectifier suited for switch mode power supplies and high frequency DC to DC converters.

Packaged in D²PAK, this device is especially intended for use in low voltage, high frequency inverters, freewheeling and polarity protection applications for automotive applications.

Table 1: Device summary

Symbol	Value
$I_{F(AV)}$	2 x 8 A
V_{RRM}	200 V
T_j (max.)	175 °C
V_F (typ.)	0.78 V
t_{rr} (typ.)	21 ns

Features

- AEC-Q101 qualified
- Low losses
- Low forward and reverse recovery time
- Low leakage current
- High junction temperature
- V_{RRM} guaranteed from -40 to +175 °C
- PPAP capable



1 Characteristics

Table 2: Absolute ratings (limiting values, per diode, at 25 °C, unless otherwise specified)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage (T _j = -40 to +175 °C)			200	V
I _{F(RMS)}	Forward rms current			26	A
I _{F(AV)}	Average forward current δ = 0.5, square wave	T _C = 150 °C	Per diode	8	A
		T _C = 140 °C	Per device	16	
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal		100	A
T _{stg}	Storage temperature range			-65 to +175	°C
T _j	Maximum operating junction temperature range			-40 to +175	°C

Table 3: Thermal parameter

Symbol	Parameter		Max. value	Unit
R _{th(j-c)}	Junction to case	Per diode	2.7	°C/W
		Per device	1.6	
R _{th(c)}	Coupling		0.5	°C/W

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_{j(\text{diode1})} = P_{(\text{diode1})} \times R_{th(j-c)} (\text{per diode}) + P_{(\text{diode2})} \times R_{th(c)}$$

Table 4: Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V _R = V _{RRM}	-		6	μA
		T _j = 125 °C		-	4	60	
V _F ⁽²⁾	Forward voltage drop	T _j = 25 °C	I _F = 8 A	-		1.10	V
		T _j = 150 °C		-	0.78	0.90	
		T _j = 25 °C	I _F = 16 A	-		1.25	
		T _j = 150 °C		-		1.05	

Notes:

⁽¹⁾Pulse test: t_p = 5 ms, $\delta < 2\%$

⁽²⁾Pulse test: t_p = 380 μs, $\delta < 2\%$

To evaluate the conduction losses, use the following equation:

$$P = 0.75 \times I_{F(AV)} + 0.01875 \times I_{F(RMS)}^2$$

Table 5: Dynamic electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
t_{rr}	Reverse recovery time	$T_j = 25\text{ °C}$	$I_F = 1\text{ A},$ $V_R = 30\text{ V},$ $di_F/dt = 100\text{ A/}\mu\text{s}$	-	21	26	ns
I_{RM}	Reverse recovery current	$T_j = 125\text{ °C}$	$I_F = 8\text{ A},$ $V_R = 160\text{ V},$ $di_F/dt = 200\text{ A/}\mu\text{s}$	-	8	10	A

1.1 Characteristics (curves)

Figure 1: Average forward power dissipation versus average forward current (square waveform)

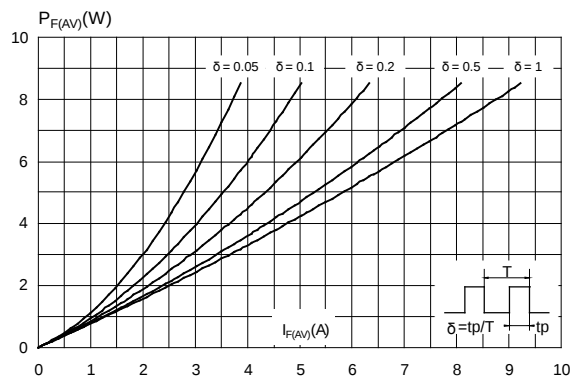


Figure 2: Forward voltage drop versus forward current (typical values)

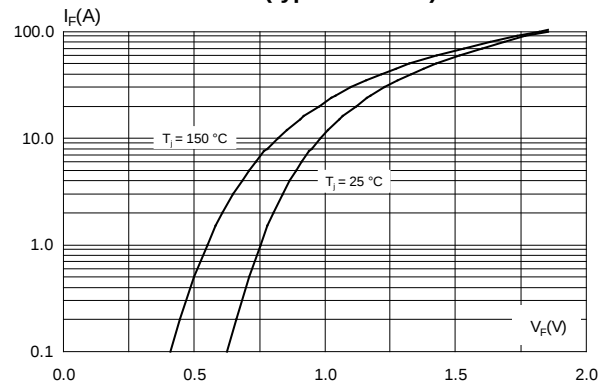


Figure 3: Forward voltage drop versus forward current (maximum values)

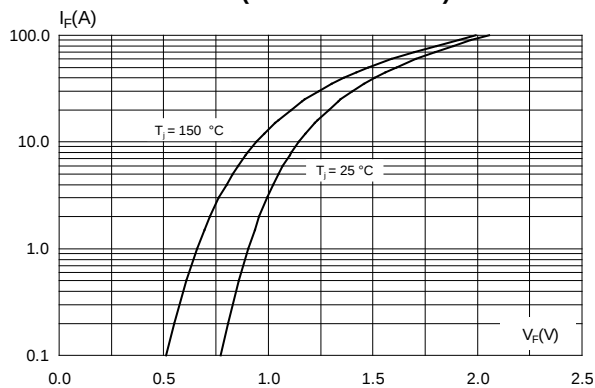


Figure 4: Relative variation of thermal impedance junction to case versus pulse duration

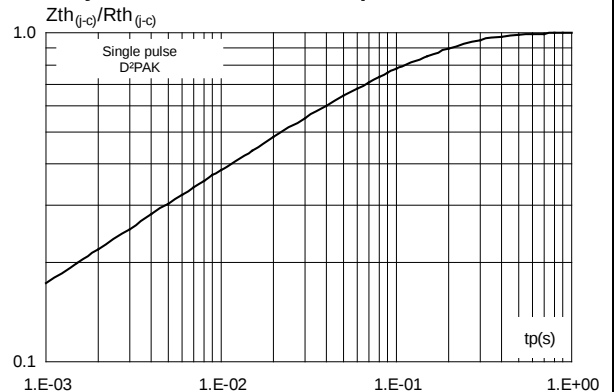


Figure 5: Junction capacitance versus reverse voltage applied (typical values, per diode)

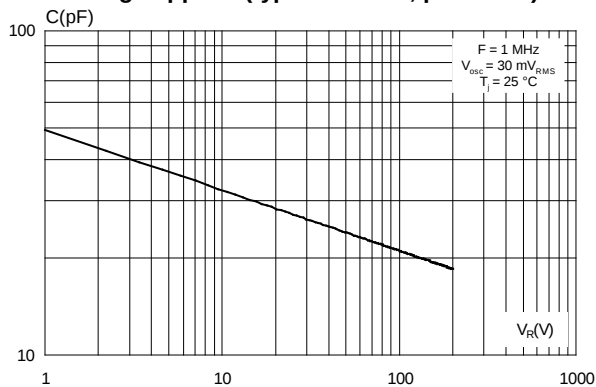


Figure 6: Reverse recovery charges versus di_F/dt (typical values, per diode)

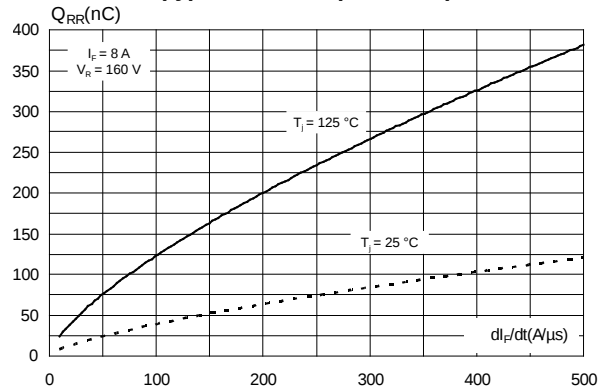


Figure 7: Reverse recovery time versus di_F/dt (typical values, per diode)

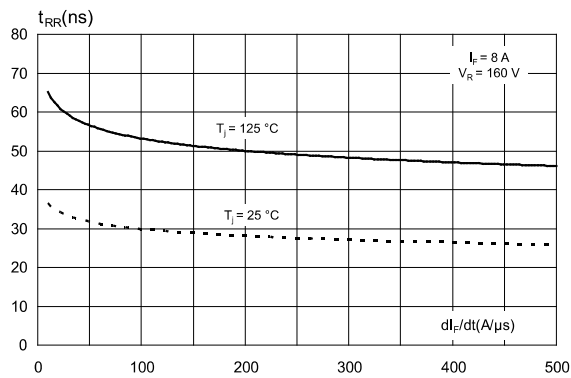


Figure 8: Peak reverse recovery current versus di_F/dt (typical values, per diode)

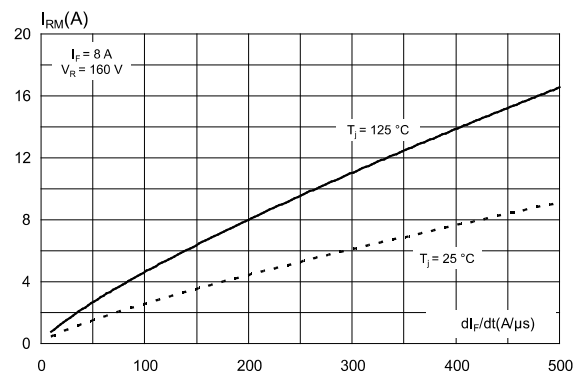


Figure 9: Softness factor versus di_F/dt (typical values, per diode)

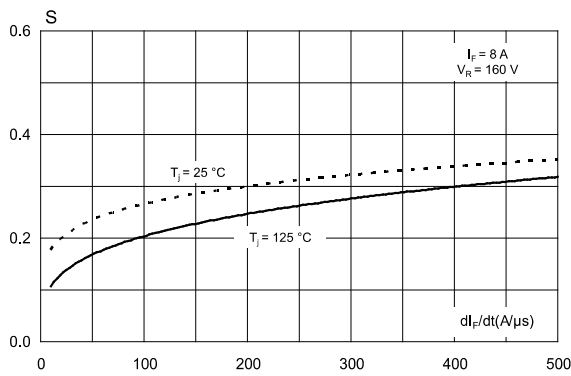


Figure 10: Dynamic parameters versus junction temperature

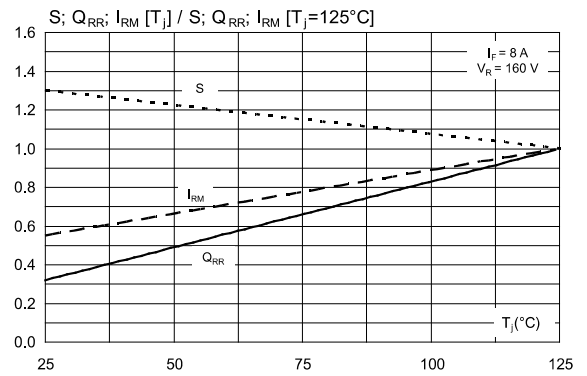
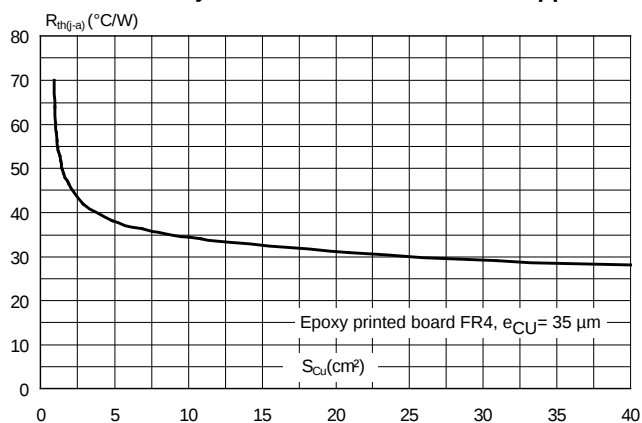


Figure 11: Thermal resistance junction to ambient versus copper surface under tab

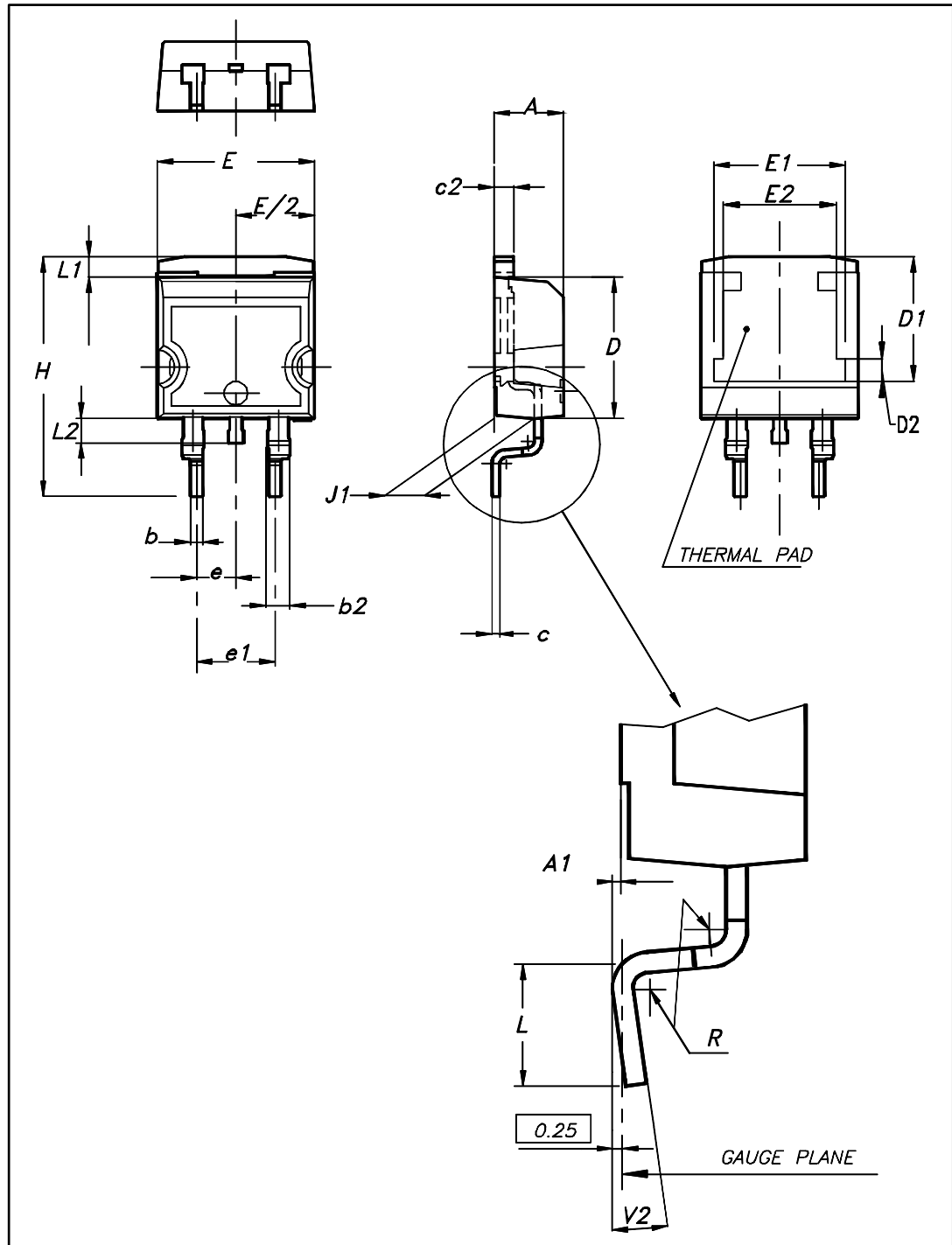


2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

- Cooling method: by conduction (C)
- Epoxy meets UL94,V0

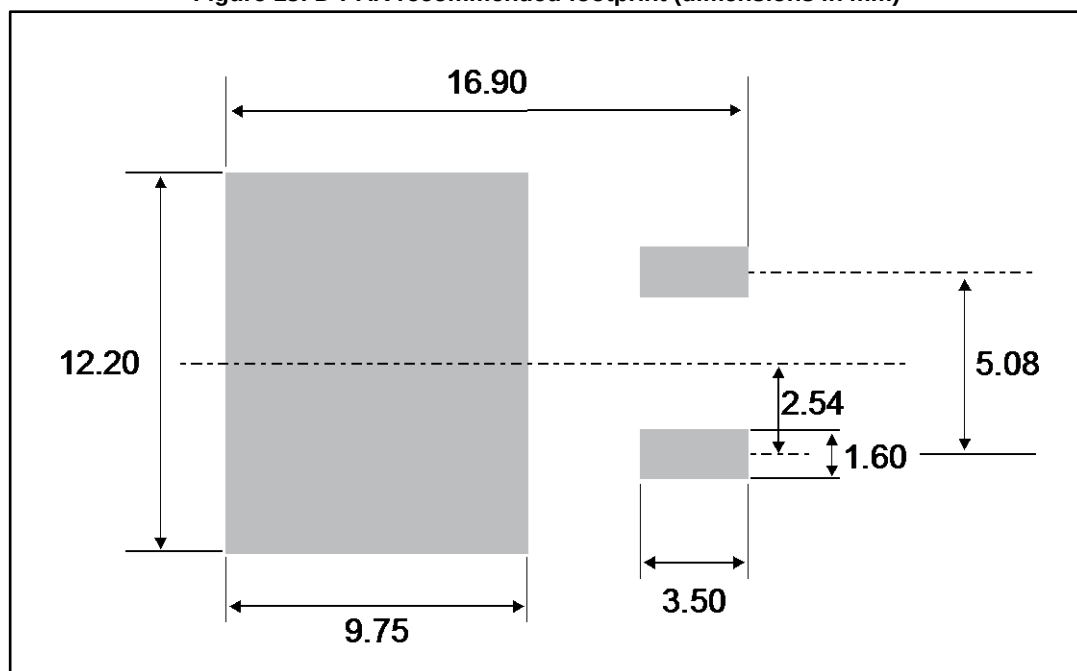
2.1 D²PAK package information

Figure 12: D²PAK package outline

This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 6: D²PAK package mechanical data

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.36	4.60	0.172	0.181
A1	0.00	0.25	0.000	0.010
b	0.70	0.93	0.028	0.037
b2	1.14	1.70	0.045	0.067
c	0.38	0.69	0.015	0.027
c2	1.19	1.36	0.047	0.053
D	8.60	9.35	0.339	0.368
D1	6.90	8.00	0.272	0.311
D2	1.10	1.50	0.043	0.060
E	10.00	10.55	0.394	0.415
E1	8.10	8.90	0.319	0.346
E2	6.85	7.25	0.266	0.282
e	2.54 typ.		0.100	
e1	4.88	5.28	0.190	0.205
H	15.00	15.85	0.591	0.624
J1	2.49	2.90	0.097	0.112
L	1.90	2.79	0.075	0.110
L1	1.27	1.65	0.049	0.065
L2	1.30	1.78	0.050	0.070
R	0.4 typ.		0.015	
V2	0°	8°	0°	8°

Figure 13: D²PAK recommended footprint (dimensions in mm)

3 Ordering information

Table 7: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STTH1602CGY-TR	STTH1602CGY	D ² PAK	1.48 g	1000	Tape and reel

4 Revision history

Table 8: Document revision history

Date	Revision	Changes
04-Dec-2017	1	Initial release.

IMPORTANT NOTICE – PLEASE READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2017 STMicroelectronics – All rights reserved